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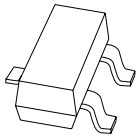
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Kind regards,

Team Nexperia



# PMEG2005CT

500 mA low  $V_F$  dual MEGA Schottky barrier rectifier

Rev. 2 — 22 June 2010

Product data sheet

## 1. Product profile

### 1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier in common cathode configuration with an integrated guard ring for stress protection, encapsulated in a SOT23 (TO-236AB) small Surface-Mounted Device (SMD) plastic package.

### 1.2 Features and benefits

- Average forward current:  $I_{F(AV)} \leq 0.5$  A
- Reverse voltage:  $V_R \leq 20$  V
- Low forward voltage
- AEC-Q101 qualified
- Small SMD plastic package

### 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- High-speed switching
- Low power consumption applications

### 1.4 Quick reference data

Table 1. Quick reference data  
 $T_j = 25$  °C unless otherwise specified.

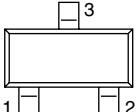
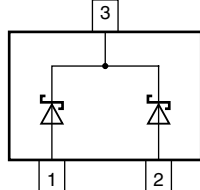
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per diode</b>						
$I_{F(AV)}$	average forward current	square wave; $\delta = 0.5$ ; $f = 20$ kHz				
		$T_{amb} \leq 100$ °C	[1]	-	-	0.5
		$T_{sp} \leq 130$ °C	-	-	0.5	A
$V_R$	reverse voltage		-	-	20	V
$V_F$	forward voltage	$I_F = 0.5$ A	-	360	390	mV
$I_R$	reverse current	$V_R = 20$ V	-	30	200	$\mu$ A

[1] Device mounted on a ceramic Printed-Circuit Board (PCB),  $Al_2O_3$ , standard footprint.



## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	anode (diode 1)		
2	anode (diode 2)		
3	common cathode		

006aaa438

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PMEG2005CT	-	plastic surface-mounted package; 3 leads	SOT23

## 4. Marking

Table 4. Marking codes

Type number	Marking code <sup>[1]</sup>
PMEG2005CT	P8*

- [1] \* = -: made in Hong Kong  
 \* = p: made in Hong Kong  
 \* = t: made in Malaysia  
 \* = W: made in China

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
<b>Per diode</b>						
$V_R$	reverse voltage	$T_j = 25\text{ °C}$	-	20	V	
$I_{F(AV)}$	average forward current	square wave; $\delta = 0.5$ ; $f = 20\text{ kHz}$				
		$T_{amb} \leq 100\text{ °C}$	[1]	-	0.5	A
		$T_{sp} \leq 130\text{ °C}$	-	-	0.5	A
$I_{FRM}$	repetitive peak forward current	$t_p \leq 1\text{ ms}$ ; $\delta \leq 0.25$	-	3.9	A	
$I_{FSM}$	non-repetitive peak forward current	square wave; $t_p = 8\text{ ms}$	[2]	-	10	A

**Table 5. Limiting values ...continued**  
 In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
<b>Per device; one diode loaded</b>						
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ °C}$	[3]	-	330	mW
			[4]	-	400	mW
			[1]	-	460	mW
$T_j$	junction temperature		-	150	°C	
$T_{amb}$	ambient temperature		-55	+150	°C	
$T_{stg}$	storage temperature		-65	+150	°C	

[1] Device mounted on a ceramic PCB,  $Al_2O_3$ , standard footprint.

[2]  $T_j = 25\text{ °C}$  prior to surge.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

## 6. Thermal characteristics

**Table 6. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
<b>Per device; one diode loaded</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]				
			[2]	-	-	375	K/W
			[3]	-	-	310	K/W
			[4]	-	-	270	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[5]	-	60	K/W	

[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses  $P_R$  are a significant part of the total power losses.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

[4] Device mounted on a ceramic PCB,  $Al_2O_3$ , standard footprint.

[5] Soldering point of cathode tab.

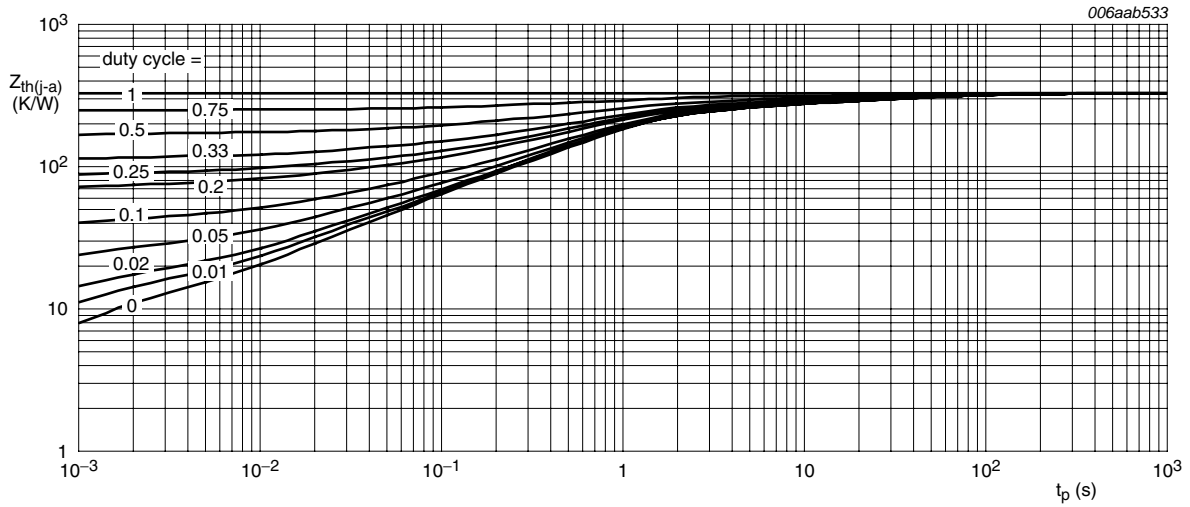


Fig 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

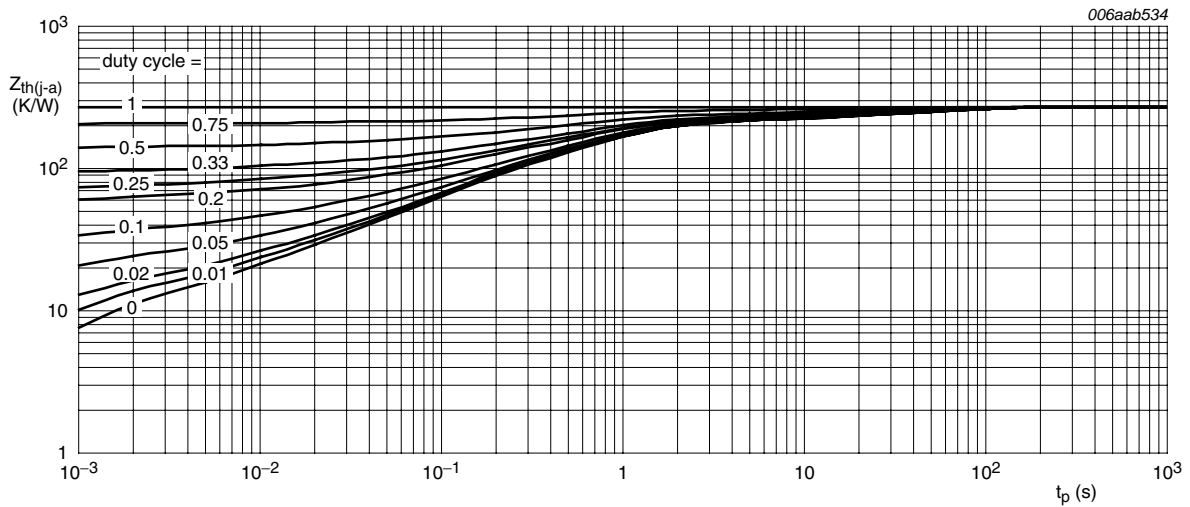
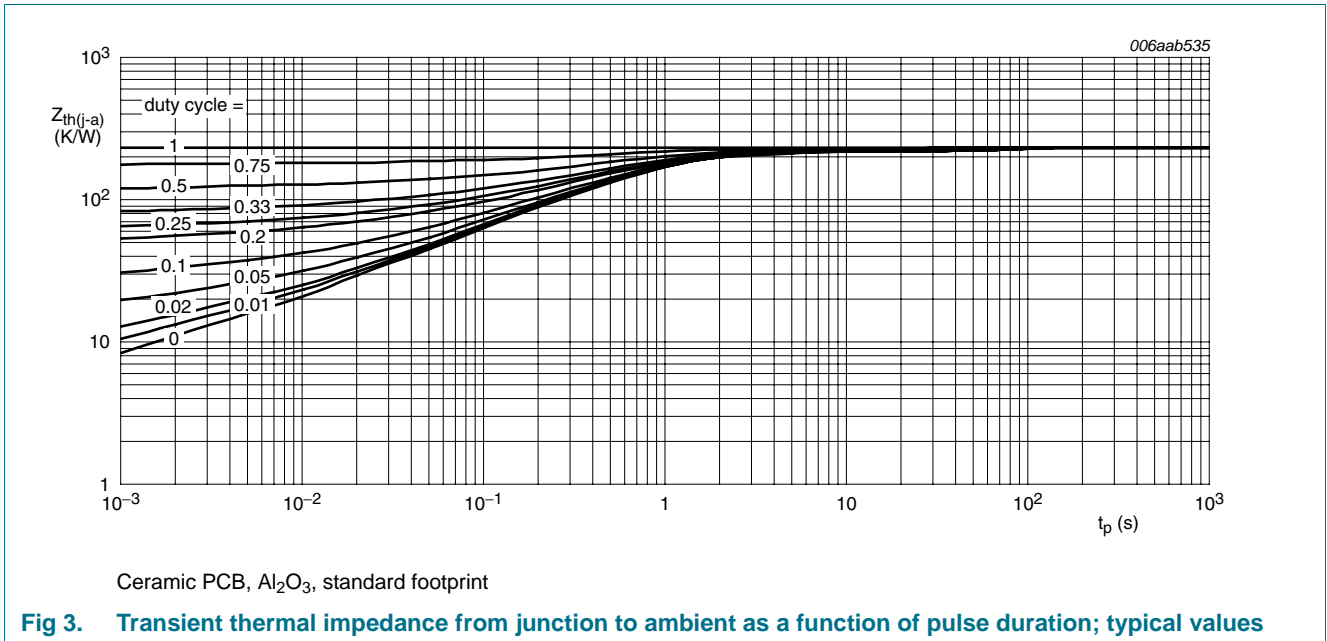


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



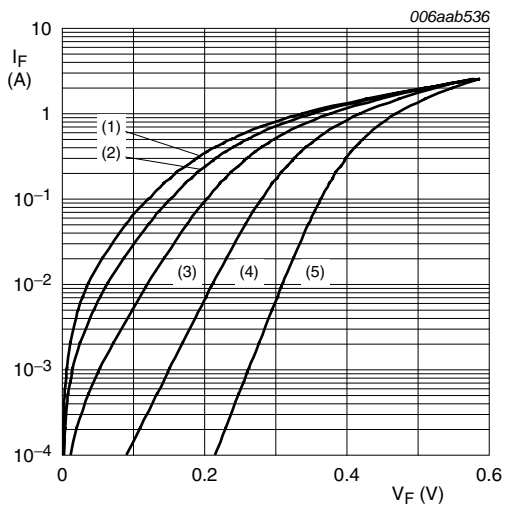
## 7. Characteristics

**Table 7. Characteristics**

$T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified.

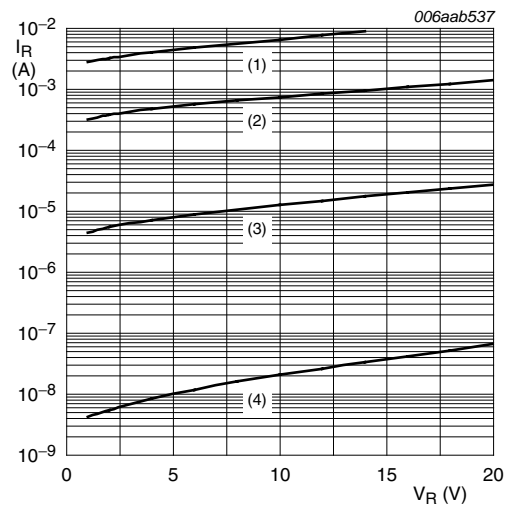
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per device</b>						
$V_F$	forward voltage	$I_F = 0.1\text{ mA}$	-	95	130	mV
		$I_F = 1\text{ mA}$	-	155	190	mV
		$I_F = 10\text{ mA}$	-	215	240	mV
		$I_F = 100\text{ mA}$	-	285	330	mV
		$I_F = 500\text{ mA}$	-	360	390	mV
$I_R$	reverse current	$V_R = 10\text{ V}$	-	11	40	$\mu\text{A}$
		$V_R = 20\text{ V}$	-	30	200	$\mu\text{A}$
$C_d$	diode capacitance	$V_R = 1\text{ V}; f = 1\text{ MHz}$	-	66	80	pF
$t_{rr}$	reverse recovery time		[1]	22	-	ns

[1] When switched from  $I_F = 10\text{ mA}$  to  $I_R = 10\text{ mA}$ ;  $R_L = 100\ \Omega$ ; measured at  $I_R = 1\text{ mA}$ .



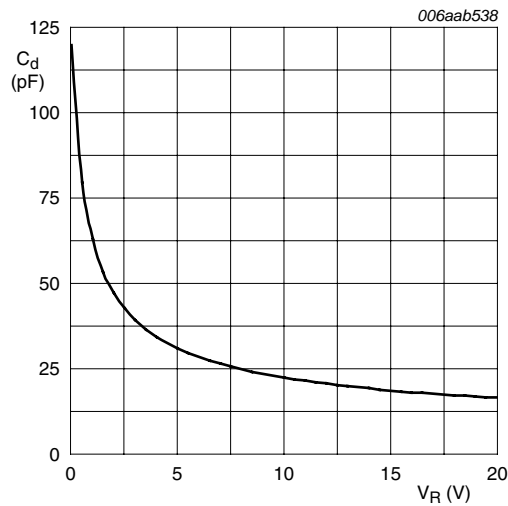
- (1)  $T_j = 150\text{ °C}$
- (2)  $T_j = 125\text{ °C}$
- (3)  $T_j = 85\text{ °C}$
- (4)  $T_j = 25\text{ °C}$
- (5)  $T_j = -40\text{ °C}$

**Fig 4. Forward current as a function of forward voltage; typical values**



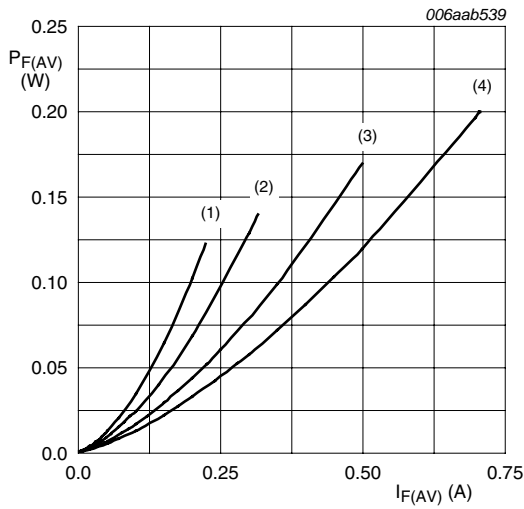
- (1)  $T_j = 125\text{ °C}$
- (2)  $T_j = 85\text{ °C}$
- (3)  $T_j = 25\text{ °C}$
- (4)  $T_j = -40\text{ °C}$

**Fig 5. Reverse current as a function of reverse voltage; typical values**



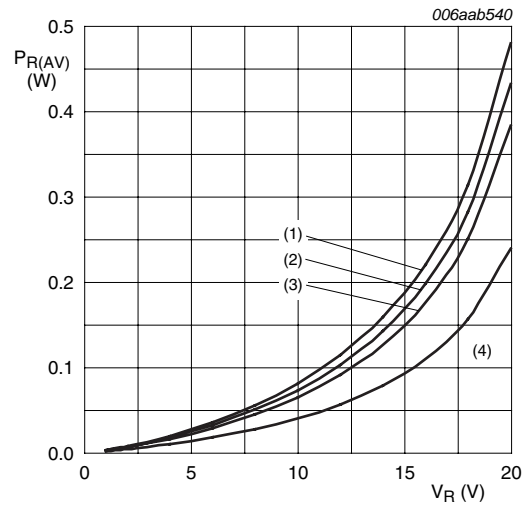
$f = 1\text{ MHz}; T_{amb} = 25\text{ °C}$

**Fig 6. Diode capacitance as a function of reverse voltage; typical values**



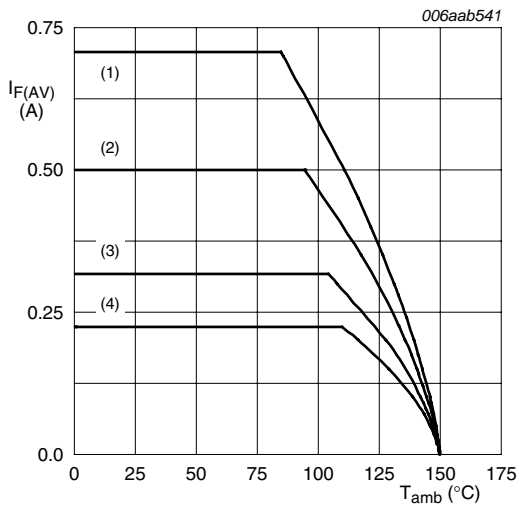
- $T_j = 150\text{ °C}$
- (1)  $\delta = 0.1$
  - (2)  $\delta = 0.2$
  - (3)  $\delta = 0.5$
  - (4)  $\delta = 1$

**Fig 7. Average forward power dissipation as a function of average forward current; typical values**



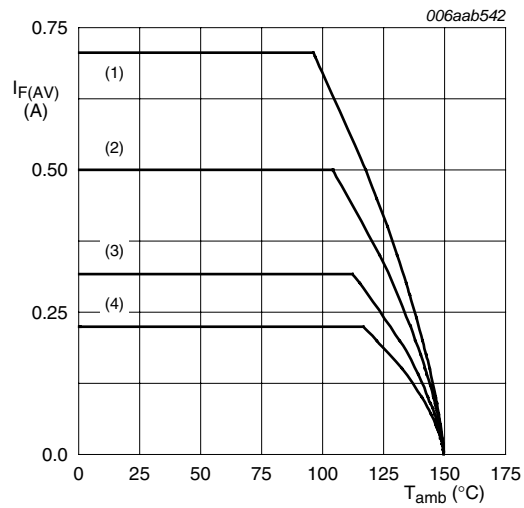
- $T_j = 125\text{ °C}$
- (1)  $\delta = 1$
  - (2)  $\delta = 0.9$
  - (3)  $\delta = 0.8$
  - (4)  $\delta = 0.5$

**Fig 8. Average reverse power dissipation as a function of reverse voltage; typical values**



- FR4 PCB, standard footprint  
 $T_j = 150\text{ °C}$
- (1)  $\delta = 1$ ; DC
  - (2)  $\delta = 0.5$ ;  $f = 20\text{ kHz}$
  - (3)  $\delta = 0.2$ ;  $f = 20\text{ kHz}$
  - (4)  $\delta = 0.1$ ;  $f = 20\text{ kHz}$

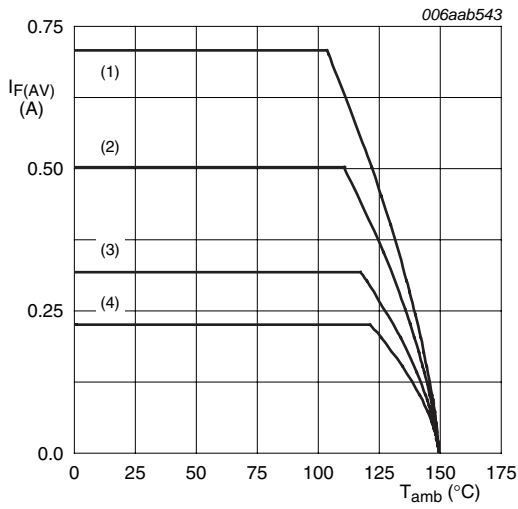
**Fig 9. Average forward current as a function of ambient temperature; typical values**



- FR4 PCB, mounting pad for cathode  $1\text{ cm}^2$   
 $T_j = 150\text{ °C}$
- (1)  $\delta = 1$ ; DC
  - (2)  $\delta = 0.5$ ;  $f = 20\text{ kHz}$
  - (3)  $\delta = 0.2$ ;  $f = 20\text{ kHz}$
  - (4)  $\delta = 0.1$ ;  $f = 20\text{ kHz}$

**Fig 10. Average forward current as a function of ambient temperature; typical values**



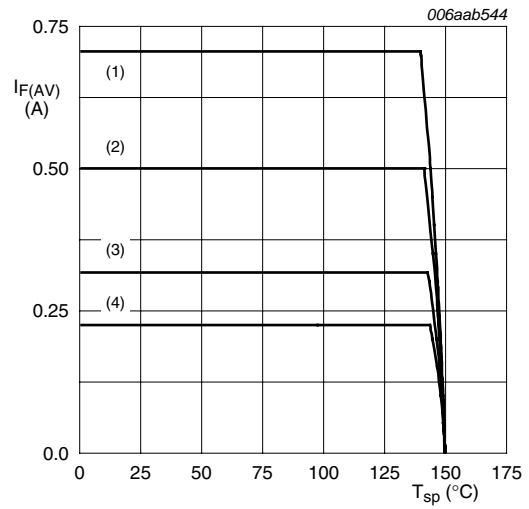


Ceramic PCB,  $Al_2O_3$ , standard footprint

$T_j = 150\text{ °C}$

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ;  $f = 20\text{ kHz}$
- (3)  $\delta = 0.2$ ;  $f = 20\text{ kHz}$
- (4)  $\delta = 0.1$ ;  $f = 20\text{ kHz}$

**Fig 11. Average forward current as a function of ambient temperature; typical values**

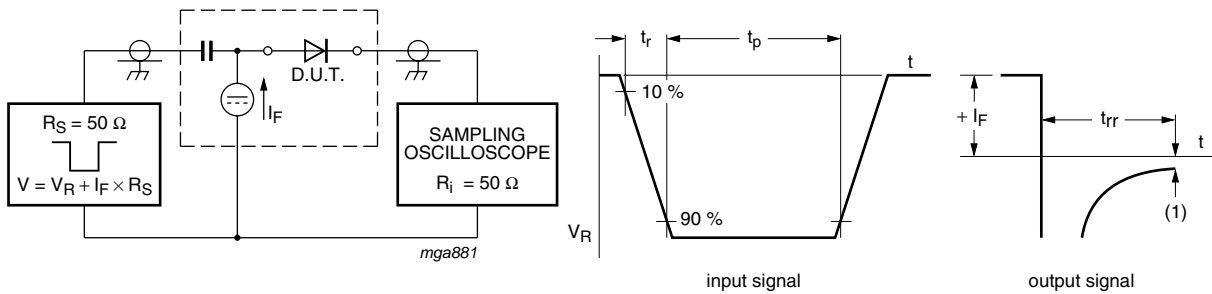


$T_j = 150\text{ °C}$

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ;  $f = 20\text{ kHz}$
- (3)  $\delta = 0.2$ ;  $f = 20\text{ kHz}$
- (4)  $\delta = 0.1$ ;  $f = 20\text{ kHz}$

**Fig 12. Average forward current as a function of solder point temperature; typical values**

## 8. Test information

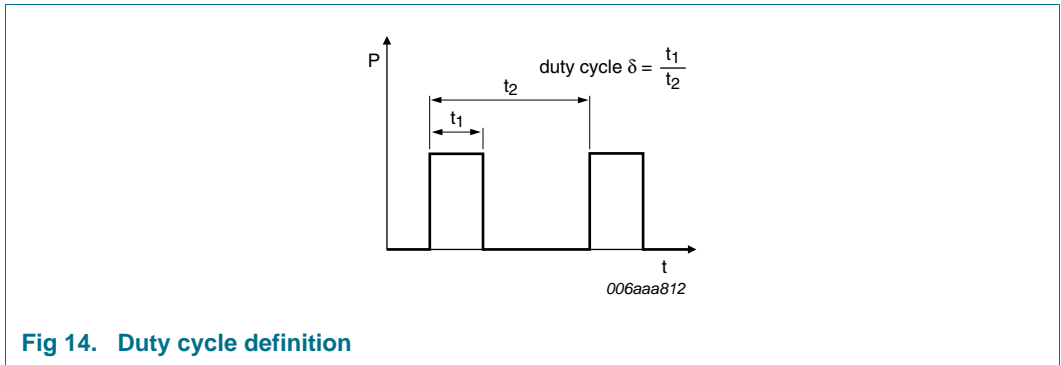


(1)  $I_R = 1\text{ mA}$

Input signal: reverse pulse rise time  $t_r = 0.6\text{ ns}$ ; reverse voltage pulse duration  $t_p = 100\text{ ns}$ ; duty cycle  $\delta = 0.05$

Oscilloscope: rise time  $t_r = 0.35\text{ ns}$

**Fig 13. Reverse recovery time test circuit and waveforms**

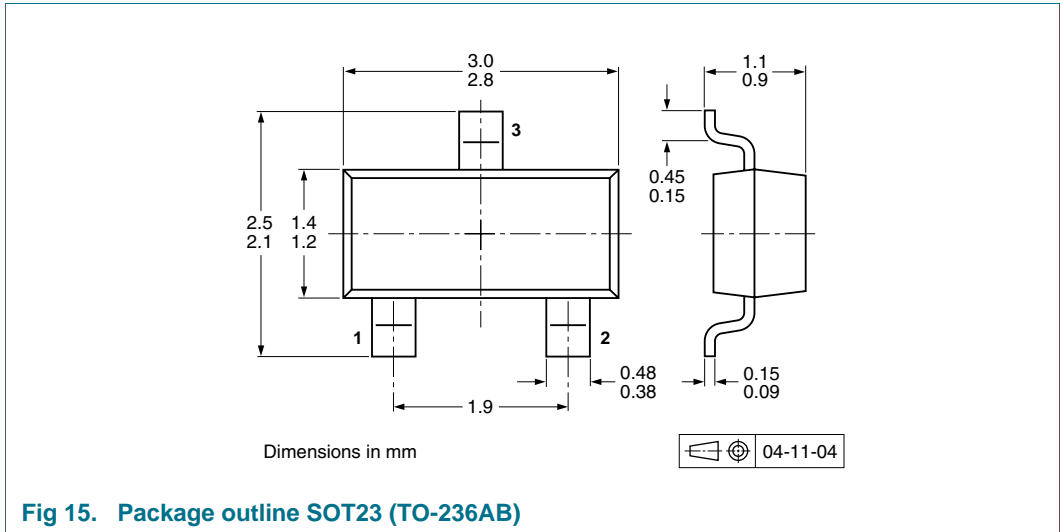


The current ratings for the typical waveforms as shown in [Figure 9](#), [10](#), [11](#) and [12](#) are calculated according to the equations:  $I_{F(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,  $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

**8.1 Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

**9. Package outline**



**10. Packing information**

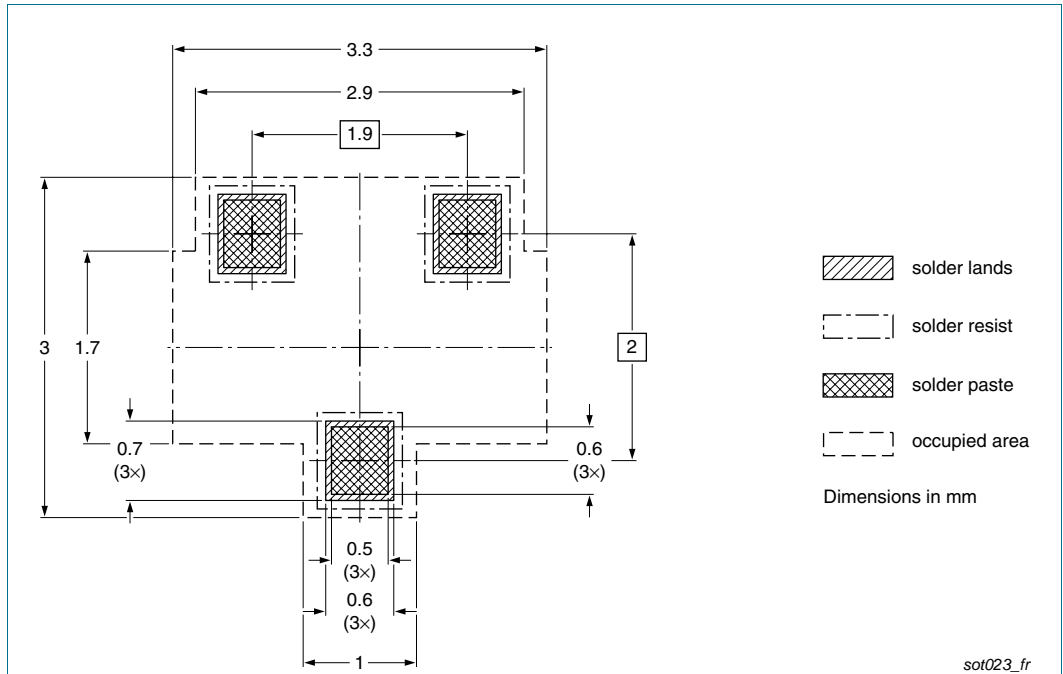
**Table 8. Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

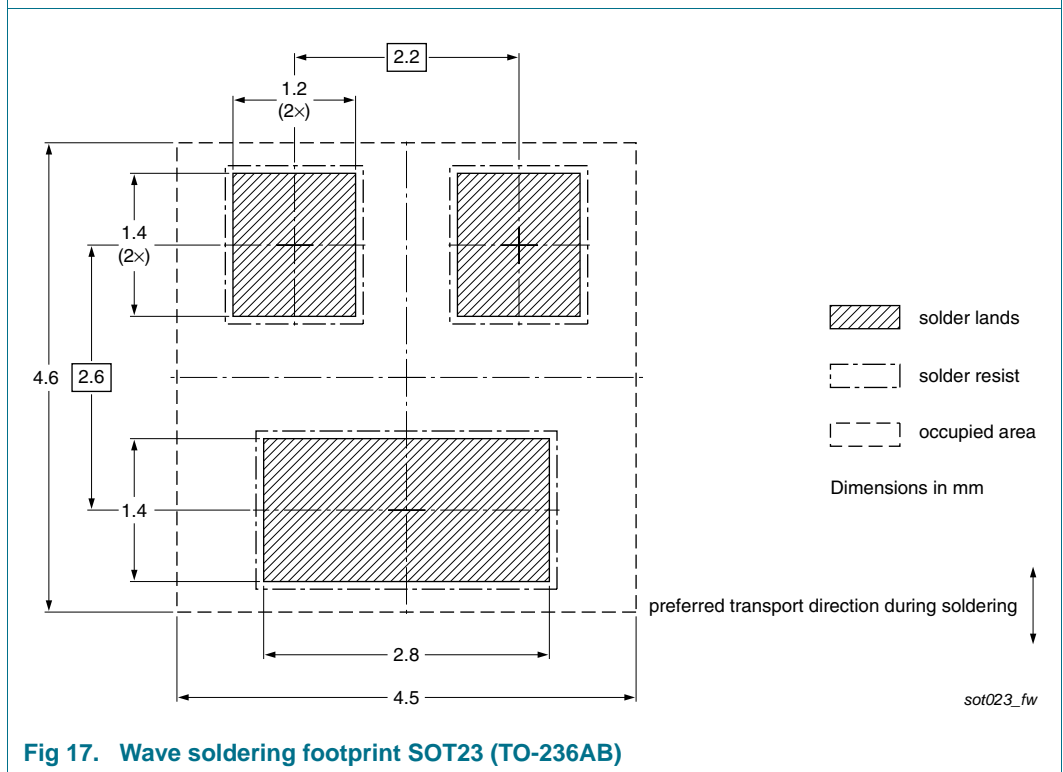
Type number	Package	Description	Packing quantity	
			3000	10000
PMEG2005CT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235

[1] For further information and the availability of packing methods, see [Section 14](#).

**11. Soldering**



**Fig 16. Reflow soldering footprint SOT23 (TO-236AB)**



**Fig 17. Wave soldering footprint SOT23 (TO-236AB)**

## 12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG2005CT v.2	20100622	Product data sheet	-	PMEG2005CT_1
Modifications:	<ul style="list-style-type: none"><li>• <a href="#">Table 2 "Pinning"</a>: Graphic symbol amended</li><li>• <a href="#">Section 13 "Legal information"</a>: updated</li></ul>			
PMEG2005CT_1	20090604	Product data sheet	-	-

## 13. Legal information

### 13.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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